## NSN 5961-00-418-6544

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View Online at https://aerobasegroup.com/nsn/5961-00-418-6544 **Inclosure Material:** Metal **Overall Length:** 0.080 inches Overall Diameter: 0.260 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, collector-to-base, emitter open and 15.0 emitter to base voltage, dc and 1.5 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 360.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Leads gold and leads silver **Precious Material:** Gold and silver **Test Data Document:** 00752-334762 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

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